TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

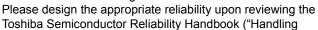
SSM3K38MFV

- High-Speed Switching Applications
- Analog Switch Applications
- 1.2V drive
- Low ON-resistance : R_{on} = 20 Ω (max) (@V_{GS} = 1.2 V)
 - : $R_{on} = 8 \Omega (max) (@V_{GS} = 1.5 V)$
 - : $R_{on} = 4 \Omega (max) (@V_{GS} = 2.5 V)$
 - : $R_{on} = 3 \Omega (max) (@V_{GS} = 4.0 V)$

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	20	V	
Gate-source voltage		V _{GSS}	±10	V	
Drain current	DC	۱ _D	180	mA	
	Pulse	I _{DP}	360		
Drain power dissipation		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

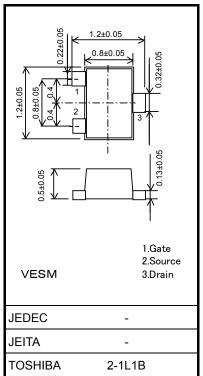
Note 1: Mounted on an FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{Cu Pad}: 0.585 \text{mm}^2)$

Electrical Characteristics (Ta = 25°C)

Chara	acteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 10$ V, $V_{DS} = 0$ V		_	_	±1	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0 \text{ V}$		20			V
Drain cutoff curre	nt	I _{DSS}	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$		_		1	μA
Gate threshold vo	oltage	V _{th}	$V_{DS} = 3 V, I_D = 1 mA$		0.4	_	1.0	V
Forward transfer	admittance	Y _{fs}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 50 \text{ mA}$	(Note2)	115			mS
			$I_{D} = 50 \text{ mA}, V_{GS} = 4 \text{ V}$	(Note2)	_	1.5	3	Ω
Drain-source ON-resistance	Design	$I_D = 50 \text{ mA}, \text{ V}_{GS} = 2.5 \text{ V}$	(Note2)	_	2	4		
	R _{DS} (ON)	$I_{D} = 5 \text{ mA}, V_{GS} = 1.5 \text{ V}$	(Note2)	_	3	8		
			$I_{D} = 5 \text{ mA}, V_{GS} = 1.2 \text{ V}$	(Note2)	_	5	20	
Input capacitance Reverse transfer capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0 V, f = 1 MHz		_	9.5		pF
		C _{rss}			_	4.1		
Output capacitan	се	C _{oss}			_	9.5		
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, \text{ I}_{D} = 50 \text{ mA}, V_{GS} = 0 \text{ to } 2.5 \text{ V}$		_	70		ns
	Turn-off time	t _{off}			_	145		
Drain-source for	ward voltage	V _{DSF}	I _D = - 180 mA, V _{GS} = 0 V	(Note2)	_	-0.9	-1.2	V

Note 2: Pulse test



Weight: 1.5 mg (typ.)

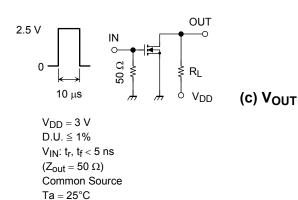
Unit: mm

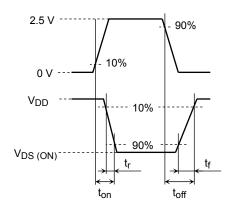
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Switching Time Test Circuit

(a) Test Circuit

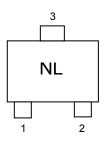
(b) V_{IN}

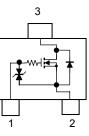




Marking

Equivalent Circuit (top view)





Notice on Usage

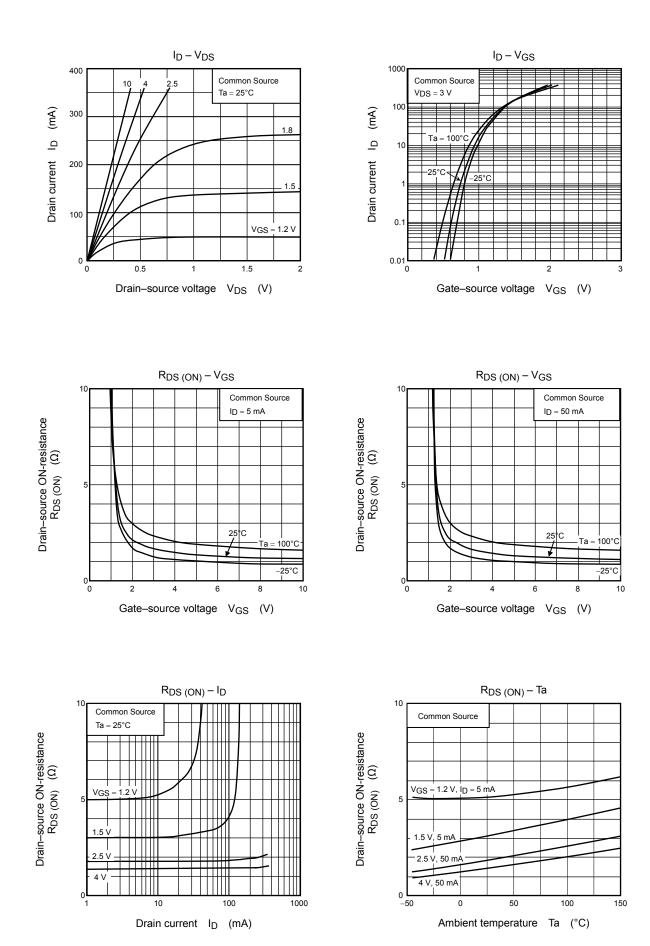
 V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = 1$ mA for this product. For normal switching operation, $V_{GS (on)}$ requires a higher voltage than V_{th} and $V_{GS (off)}$ requires a lower voltage than V_{th} . (The relationship can be established as follows: $V_{GS (off)} < V_{th} < V_{GS (on)}$.)

Take this into consideration when using the device.

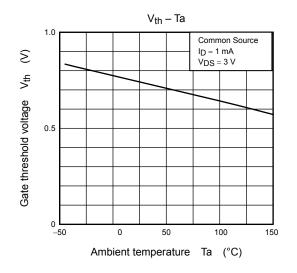
Handling Precaution

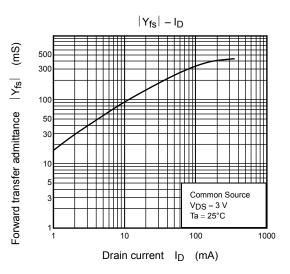
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

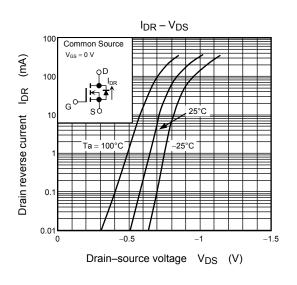
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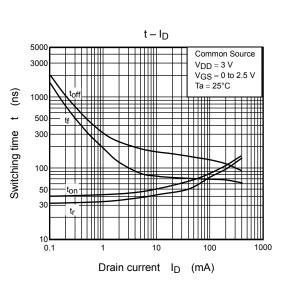


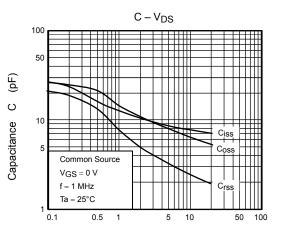
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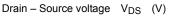


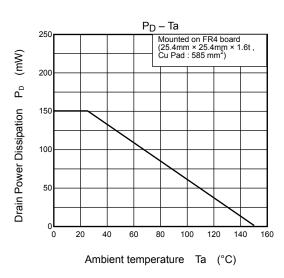












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20070701-EN GENERAL

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